

SOP-8

MOS

Complementary Enhancement MOSFET in a SOP-8 Plastic Package.

N-channel

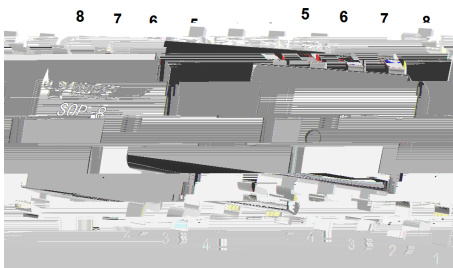
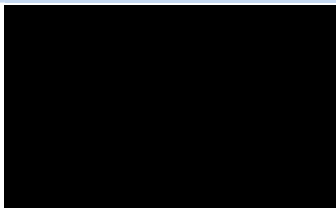
P-channel

 $V_{DS}(V)=40V$
 $V_{DS}(V)=-40V$
 $I_D=8A(T_C=25^\circ C)$
 $I_D=-7A(T_C=25^\circ C)$
 $I_{JFEZ3}, d \Delta M_{J4}(' MZ'$
 $I_{JFEZ3^*}, d \Delta M_{J4}(\$' MZ'$
 $I_{JFEZ3+}, d \Delta M_{J4}+%MZ'$
 $I_{JFEZ3-}, d \Delta M_{J4} \$+%MZ'$

HF Product.

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These devices are well suited for high efficiency switching DC/DC converters and switch mode power supplies. And suitable for use as a load switch or in PWM applications.



PIN 1	S1	PIN 2	G1	PIN 3	S2	PIN 4	G2
PIN 5	D2	PIN 6	D2	PIN 7	D1	PIN 8	D1

See Marking Instructions.

Parameter	Symbol		Rating		Unit
			N-channel	P-channel	
Drain-Source Voltage	V_{DSS}		40	-40	V
Gate-Source Voltage	V_{GSS}		±20		V
Continuous Drain Current	$I_D(T_C=25^\circ\text{C})$		8	-7	A
Continuous Drain Current	$I_D(T_A=25^\circ\text{C})$		6	-5	A
Pulsed Drain Current	I_{DM}		20	-20	A
Power Dissipation	$P_D(T_C=25^\circ\text{C})$		3.5	3.5	W
Power Dissipation	$P_D(T_A=25^\circ\text{C})$		2	2	W
Maximum Junction-to-Ambient	R_{JA}	t 10s	62.5		/W
	R_{JA}	Steady-State	110		/W
Maximum Junction-to-Case	R_{JC}	Steady-State	35.7		/W
Junction and Storage Temperature Range	T_J, T_{STG}		-55 to +150		

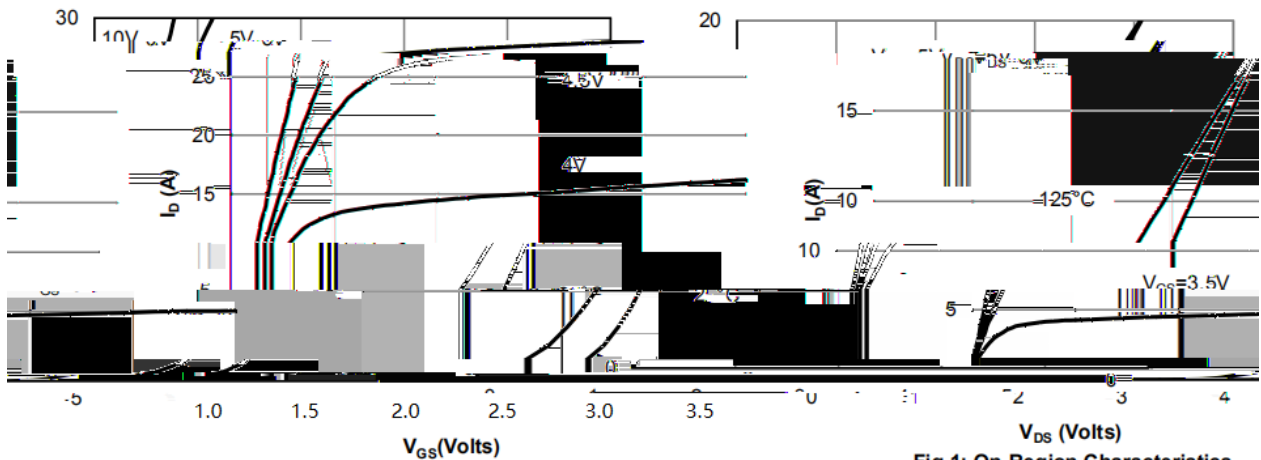


Fig 1: On-Region Characteristics

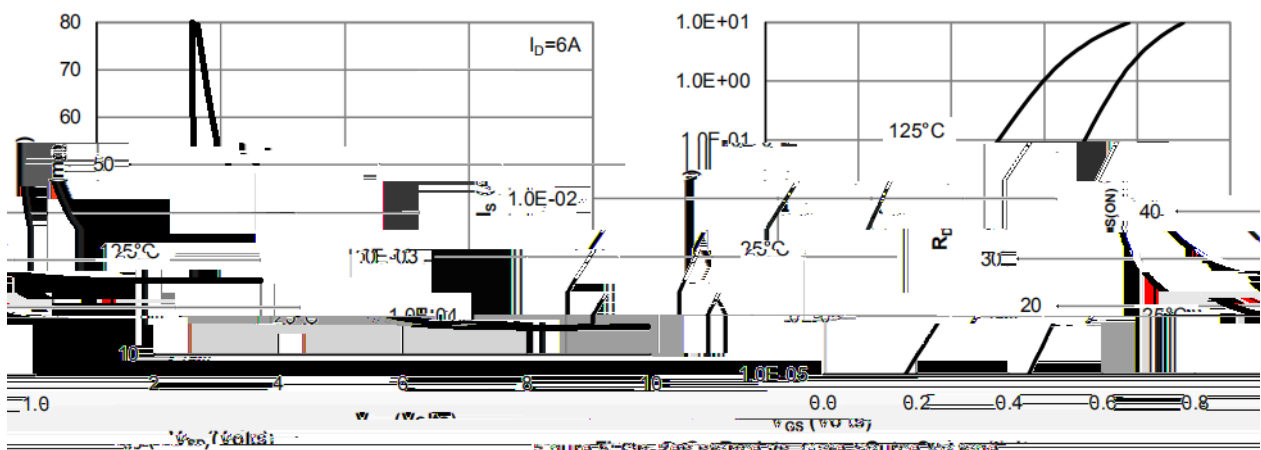
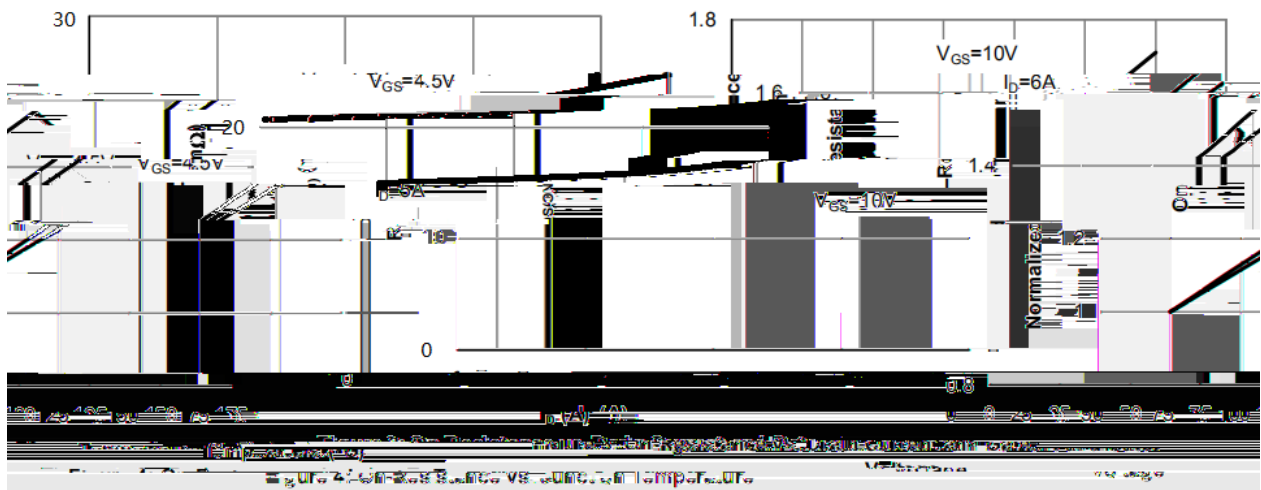
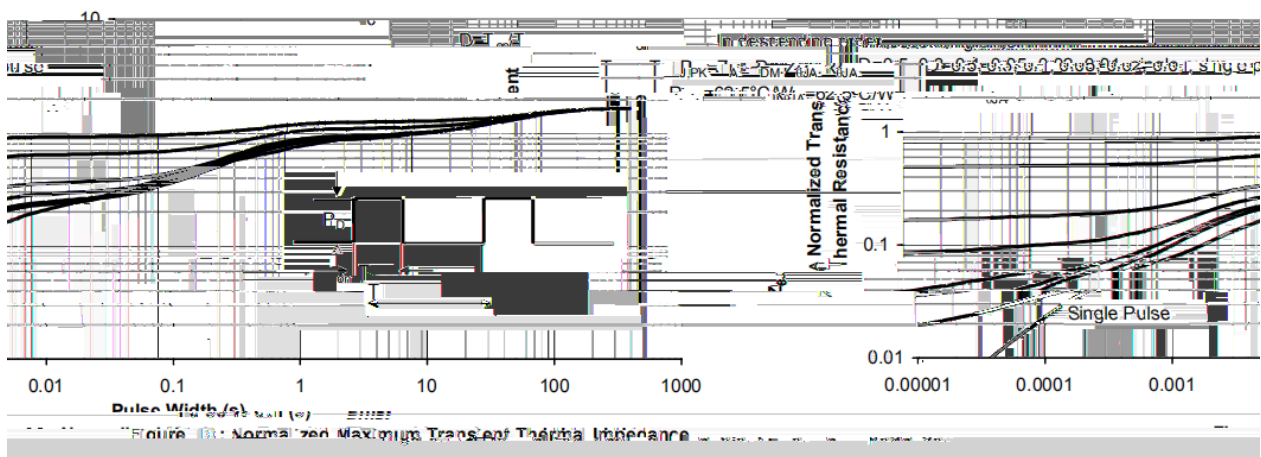
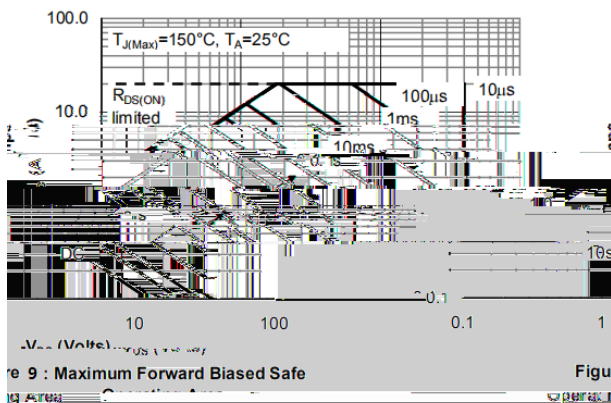
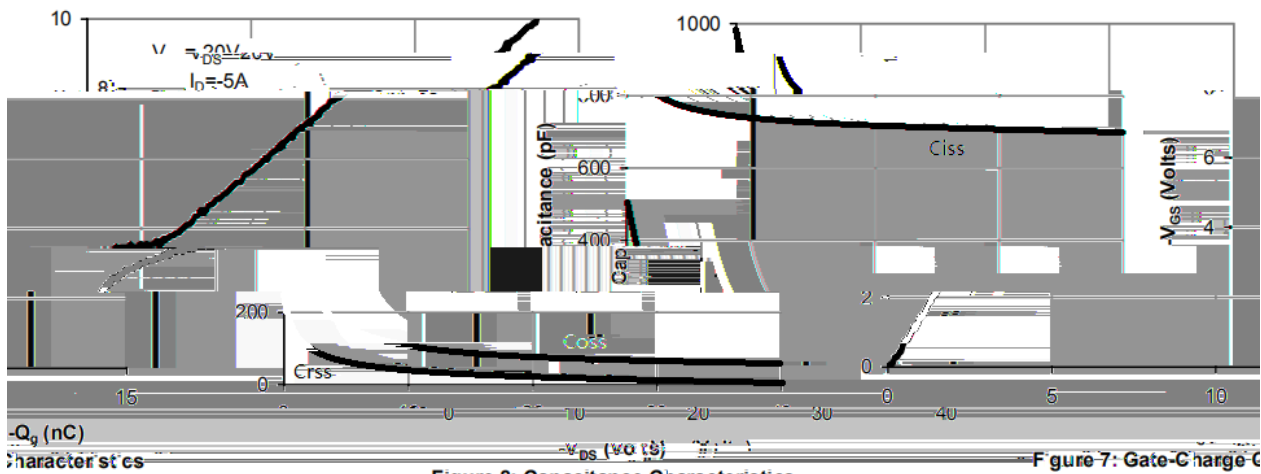
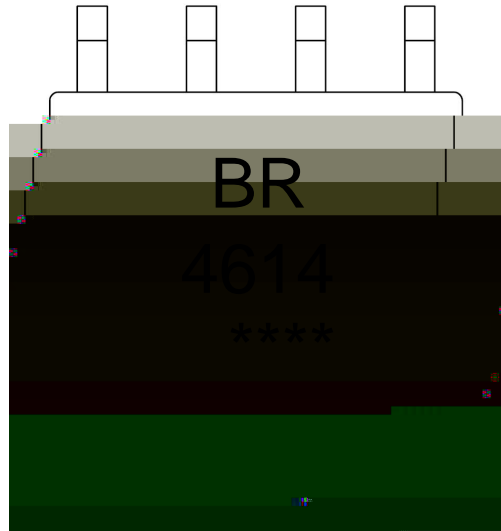


Figure 3: On-Region Characteristics

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V$ $I_D=-250\mu A$	-40	-46		V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-40V$ $V_{GS}=0V$			-1.0	μA
		$V_{DS}=-40V$ $V_{GS}=0V$ $T_J=55$			-5.0	μA
Gate-Body leakage current	I_{GSS}	$V_{GS}=\pm 20V$ $V_{DS}=0V$			± 100	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=-250\mu A$	-1.4	-1.6	-3.0	V
On state drain current	$I_{D(on)}$	$V_{DS}=-5V$ $V_{GS}=-10V$	6			A
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=-10V$ $I_D=-5.0A$		32	35	m
		$V_{GS}=-4.5V$ $I_D=-2.0A$		49	60	m
Forward Transconductance	g_{FS}	V				





BR

4614

Note:

BR: Company Code

4614: Product Type Code

****: Lot No. Code, code change with Lot No

Rev.B May.-2025